



FEATURES:

- SUPER MINI RECTIFIER IN A DIODE CASE
- HIGH CURRENT DENSITY
- HIGH RELIABILITY
- SPECIAL SELECTIONS AVAILABLE
- ROBUST GLASS CONSTRUCTION
- SUPERIOR LOT TO LOT CONSISTENCY

## **DESCRIPTION:**

The CENTRAL SEMICONDUCTOR 0.5 amp leadless glass silicon rectifier is a high quality, well constructed, highly reliable component designed for use in all types of commercial, industrial, entertainment, computer, and automotive applications where space is critical.

## MAXIMUM RATINGS: (TA=25°C unless otherwise noted)

		CLLRH	CLLRH	CLLRH	
	SYMBOL	<u>-02</u>	-04	<u>-06</u>	UNITS
Peak Repetitive Reverse Voltage	VRRM	200	400	600	V
DC Blocking Voltage	VR	200	400	600	V
RMS Reverse Voltage	V <sub>R</sub> (RMS)	140	280	420	V
Average Forward Current (TL=80°C) Peak Forward Surge Current	IO		0.5		A
(Non-Repetitive, 8.3ms surge) Operating and Storage	IFSM		10		A
Junction Temperature	TJ,Tstg		-65 to +175	5	°C

## ELECTRICAL CHARACTERISTICS: (TA=25°C unless otherwise noted)

SYMBOL	<b>TEST CONDITIONS</b>	MIN	MAX	UNITS
VF	I <sub>F</sub> =Rated I <sub>O</sub>		1.1	V
I <sub>R</sub>	V <sub>R</sub> =Rated V <sub>RRM</sub>		200	nA
I <sub>R</sub>	V <sub>R</sub> =Rated V <sub>RRM</sub> , T <sub>A</sub> =150°C		25	μA
CJ	V <sub>R</sub> =4.0V, f=1.0MHz		10	pF

All dimensions in inches (mm).

